# **GTM**

# **CORPORATION**

ISSUED DATE :2005/01/20 REVISED DATE :

## GJUR0620CT

# SUPER FAST RECOVERY RECTIFIER VOLTAGE 200V, CURRENT 6A

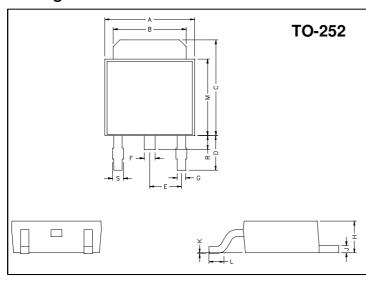
#### **Description**

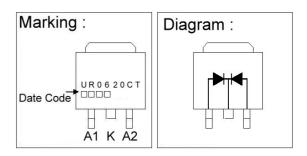
The GJUR0620CT consists of two super fast recovery rectifier diodes with common Cathodes.

#### **Features**

- \*Glass passivated chip junctions
- \*Low power loss
- \*Low forward voltage, high current capability
- \*High surge current capability
- \*Super fast recovery times for high efficiency
- \*High temperature soldering guaranteed: 260°C/10 seconds at terminals

### **Package Dimensions**





REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	nLI.	Min.	Max.
Α	6.40	6.80	G	0.50	0.70
В	5.20	5.50	Η	2.20	2.40
С	6.80	7.20	J	0.45	0.55
D	2.20	2.80	K	0	0.15
Е	2.30 REF.		L	0.90	1.50
F	0.70	0.90	М	5.40	5.80
S	0.60	0.90	R	0.80	1.20

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Ratings	Unit	
Operating and Storage Temperature	Tj, Tstg	-55 ~ +150	°C	
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	200	V	
Maximum RMS Voltage	V <sub>RMS</sub>	140	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	200	V	
Maximum Average Forward Rectified Current	$I_{O}$	6	А	
Peak Forward Surge Current 8.3ms single half sine-wave Superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	100	А	
Typical Junction Capacitance per leg <sup>1</sup>	CJ	30	pF	
Typical thermal resistance <sup>2</sup>	Rθ <sub>JC</sub>	5.0	°C/W	
Total Power Dissipation	P <sub>D</sub>		mW	

### Electrical Characteristics at Ta = 25°C

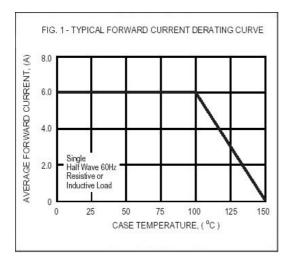
Characteristic	Symbol	Min.	Max.	Unit	Test Conditions
Forward Voltage	VF	-	0.975	V	IF=3A
Reverse Breakdown	VR	200	-	V	IR=100uA
Reverse Current at rated DC	IR TC=25°C	-	5	uA	VR=200V
blocking voltage per leg	IR TC=100°C	=	150	uA	V N=200 V
Reverse Recovery Time per leg	trr	=	35	ns	IF=0.5A, Ir=-1.0A, Irr=-0.25A

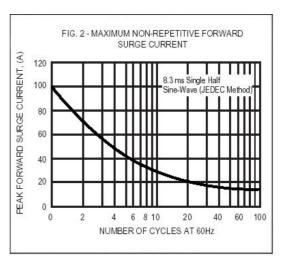
Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 volts.

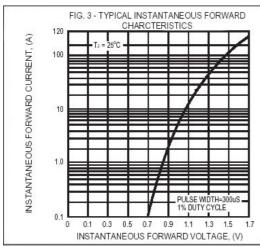
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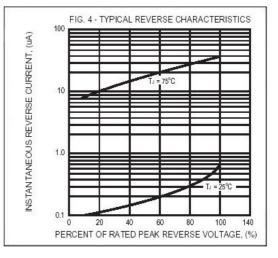
<sup>2.</sup> Thermal resistance from junction to case per leg mounted on heatsink.

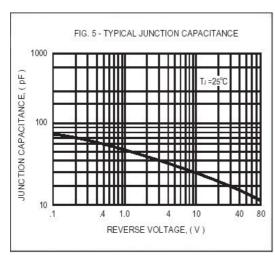
#### **Characteristics Curve**











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